Inverter

Rev. 5 — 25 September 2013

1. General description

The 74HC1G04; 74HCT1G04 is a single inverter. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - ◆ For 74HC1G04: CMOS level
 - ◆ For 74HCT1G04: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | | |
|-------------|-------------------|--------|---|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74HC1G04GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; | SOT353-1 | | | | | |
| 74HCT1G04GW | | | body width 1.25 mm | | | | | | |
| 74HC1G04GV | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads | SOT753 | | | | | |
| 74HCT1G04GV | | | | | | | | | |

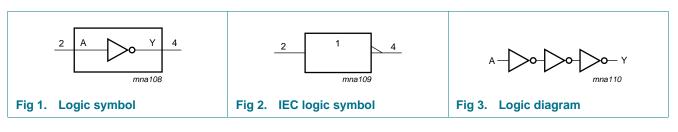


4. Marking

| Table 2. Marking codes | |
|--------------------------|------------------------|
| Type number | Marking ^[1] |
| 74HC1G04GW | HC |
| 74HCT1G04GW | ТС |
| 74HC1G04GV | H04 |
| 74HCT1G04GV | T04 |

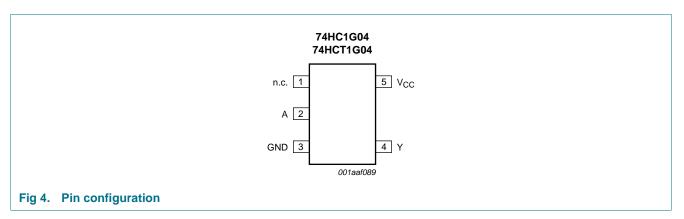
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

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| Table 3. | Pin description | |
|-----------------|-----------------|----------------|
| Symbol | Pin | Description |
| n.c. | 1 | not connected |
| A | 2 | data input |
| GND | 3 | ground (0 V) |
| Y | 4 | data output |
| V _{CC} | 5 | supply voltage |

74HC_HCT1G04
Product data sheet

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7. Functional description

Table 4. Function table

H = *HIGH* voltage level; *L* = *LOW* voltage level

| Input | Output |
|-------|--------|
| Α | Y |
| L | Н |
| Н | L |

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|-------|-------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | $V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V | - | ±20 | mA |
| Ι _{ΟΚ} | output clamping current | $V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V | - | ±20 | mA |
| Ι _Ο | output current | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ | - | ±12.5 | mA |
| I _{CC} | supply current | | - | 25 | mA |
| I _{GND} | ground current | | -25 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \ ^{\circ}C \text{ to } +125 \ ^{\circ}C$ | [2] _ | 200 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C, the value of P_{tot} derates linearly with 2.5 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter Conditions | | 7 | 74HC1G04 | | | 74HCT1G04 | | |
|------------------|-----------------------|------------------|-----|----------|-----------------|-----|-----------|-----------------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| Vo | output voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise | $V_{CC} = 2.0 V$ | - | - | 625 | - | - | - | ns/V |
| | and fall rate | $V_{CC} = 4.5 V$ | - | - | 139 | - | - | 139 | ns/V |
| | | $V_{CC} = 6.0 V$ | - | - | 83 | - | - | - | ns/V |

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

| Symbol | Parameter | Conditions | -40 | °C to +8 | 35 °C | −40 °C 1 | Unit | |
|----------------------------------|--------------------------|---|------|----------|-------|-----------------|------|----|
| | | | Min | Тур | Max | Min | Max | |
| For type | 74HC1G04 | | | | | | | |
| VIH | HIGH-level input | $V_{CC} = 2.0 V$ | 1.5 | 1.2 | - | 1.5 | - | V |
| | voltage | $V_{CC} = 4.5 V$ | 3.15 | 2.4 | - | 3.15 | - | V |
| | | $V_{CC} = 6.0 V$ | 4.2 | 3.2 | - | 4.2 | - | V |
| V _{IL} | LOW-level input | $V_{CC} = 2.0 V$ | - | 0.8 | 0.5 | - | 0.5 | V |
| | voltage | $V_{CC} = 4.5 V$ | - | 2.1 | 1.35 | - | 1.35 | V |
| | | $V_{CC} = 6.0 V$ | - | 2.8 | 1.8 | - | 1.8 | V |
| V _{OH} | HIGH-level output | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | |
| | voltage | $I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$ | 1.9 | 2.0 | - | 1.9 | - | V |
| | | $I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$ | 4.4 | 4.5 | - | 4.4 | - | V |
| | | $I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$ | 5.9 | 6.0 | - | 5.9 | - | V |
| | | I_{O} = -2.0 mA; V_{CC} = 4.5 V | 4.13 | 4.32 | - | 3.7 | - | V |
| | | I_{O} = -2.6 mA; V_{CC} = 6.0 V | 5.63 | 5.81 | - | 5.2 | - | V |
| V _{OL} LOW-level output | LOW-level output | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | |
| | voltage | $I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | I_{O} = 2.0 mA; V_{CC} = 4.5 V | - | 0.15 | 0.33 | - | 0.4 | V |
| | | I_{O} = 2.6 mA; V_{CC} = 6.0 V | - | 0.16 | 0.33 | - | 0.4 | V |
| I | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V | - | - | 1.0 | - | 1.0 | μA |
| I _{CC} | supply current | $\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$ | - | - | 10 | - | 20 | μΑ |
| Cı | input capacitance | | - | 1.5 | - | - | - | pF |
| For type | 74HCT1G04 | | | | | | | |
| V _{IH} | HIGH-level input voltage | V_{CC} = 4.5 V to 5.5 V | 2.0 | 1.6 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V_{CC} = 4.5 V to 5.5 V | - | 1.2 | 0.8 | - | 0.8 | V |
| V _{он} | HIGH-level output | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | |
| | voltage | I_{O} = -20 μ A; V_{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | V |
| | | $I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | 4.13 | 4.32 | - | 3.7 | - | V |
| V _{OL} | LOW-level output | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | |
| | voltage | $I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | I_{O} = 2.0 mA; V_{CC} = 4.5 V | - | 0.15 | 0.33 | - | 0.4 | V |
| I | input leakage current | $V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$ | - | - | 1.0 | - | 1.0 | μA |
| | | | | | | | | |

| Table 7. | Static characteristics continued | |
|----------|----------------------------------|--|
|----------|----------------------------------|--|

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

| Symbol | Parameter | Conditions | –40 °C to +85 °C | | | −40 °C t | Unit | |
|-----------------|---------------------------|---|------------------|-----|-----|-----------------|------|----|
| | | | Min | Тур | Max | Min | Max | |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 10 | - | 20 | μA |
| ΔI_{CC} | additional supply current | per input; V_{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A | - | - | 500 | - | 850 | μA |
| CI | input capacitance | | - | 1.5 | - | - | - | pF |

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 6.0$ ns; All typical values are measured at $T_{amb} = 25$ °C. For test circuit, see <u>Figure 6</u>

| Symbol | Parameter | Conditions | | -40 | °C to +8 | 5 °C | −40 °C t | Unit | |
|-----------------|-------------------------------|---|------------|-----|----------|------|-----------------|------|----|
| | | | | Min | Тур | Max | Min | Max | |
| For type | 74HC1G04 | | | | | | | | |
| t _{pd} | propagation delay | A to Y; see Figure 5 | <u>[1]</u> | | | | | | |
| | | $V_{CC} = 2.0 \text{ V}; C_{L} = 50 \text{ pF}$ | | - | 25 | 105 | - | 135 | ns |
| | | $V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$ | | - | 9 | 21 | - | 27 | ns |
| | | $V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$ | | - | 7 | - | - | - | ns |
| | | $V_{CC} = 6.0 \text{ V}; C_{L} = 50 \text{ pF}$ | | - | 8 | 18 | - | 23 | ns |
| C _{PD} | power dissipation capacitance | $V_{I} = GND$ to V_{CC} | [2] | - | 16 | - | - | - | pF |
| For type | 74HCT1G04 | | | | | | | | |
| t _{pd} | propagation delay | A to Y; see Figure 5 | <u>[1]</u> | | | | | | |
| | | $V_{CC} = 4.5 \text{ V}; C_{L} = 50 \text{ pF}$ | | - | 10 | 24 | - | 27 | ns |
| | | $V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$ | | - | 8 | - | - | - | ns |
| C _{PD} | power dissipation capacitance | V_{I} = GND to V_{CC} – 1.5 V | <u>[2]</u> | - | 18 | - | - | - | pF |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $[2] \quad C_{PD} \text{ is used to determine the dynamic power dissipation } P_D (\mu W). \\ P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$

 $f_i = input frequency in MHz$

 $f_o = output frequency in MHz$

 C_L = output load capacitance in pF

 V_{CC} = supply voltage in Volts

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

12. Waveforms

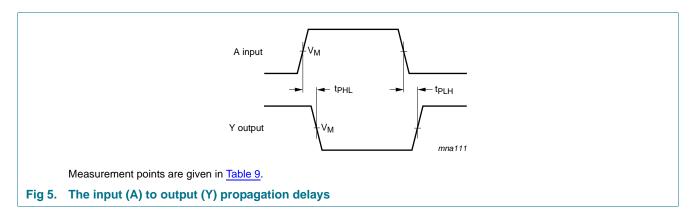


Table 9.Measurement points

| Туре | VI | V _M |
|-----------|------------------------|---------------------|
| 74HC1G04 | GND to V _{CC} | $0.5 \times V_{CC}$ |
| 74HCT1G04 | GND to 03 V | 1.3 V |

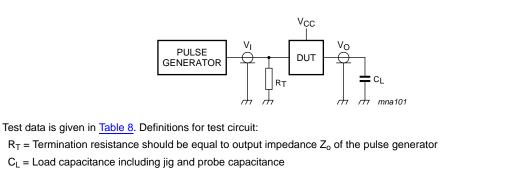


Fig 6. Load circuitry for switching times

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13. Package outline

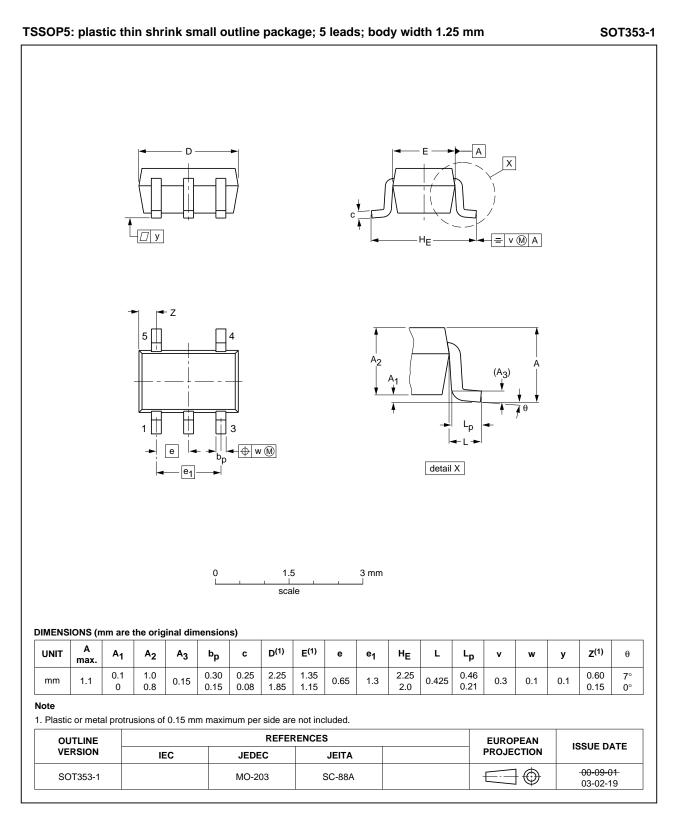


Fig 7. Package outline SOT353-1 (TSSOP5)

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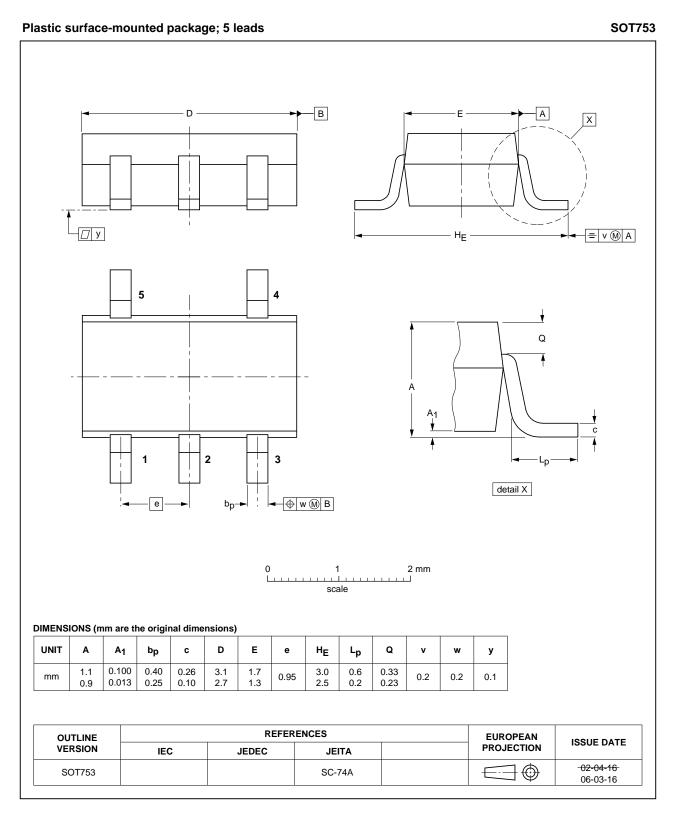


Fig 8. Package outline SOT753 (SC-74A)

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74HC_HCT1G04

14. Abbreviations

| Table 10. Abbreviations | | | |
|-------------------------|-----------------------------|--|--|
| Acronym | Description | | |
| DUT | Device Under Test | | |
| TTL | Transistor-Transistor Logic | | |

15. Revision history

Table 11.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|------------------|---|-------------------------------|---------------|------------------|--|--|
| 74HC_HCT1G04 v.5 | 20130925 | Product data sheet | - | 74HC_HCT1G04 v.4 | | |
| Modifications: | Section 1 " | General description" updated. | | | | |
| 74HC_HCT1G04 v.4 | 20070716 | Product data sheet | - | 74HC_HCT1G04 v.3 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | Package SOT353 changed to SOT353-1 in <u>Table 1</u> and <u>Figure 7</u>. | | | | | |
| | Quick Reference Data and Soldering sections removed. | | | | | |
| | <u>Section 2 "Features and benefits"</u> updated. | | | | | |
| 74HC_HCT1G04 v.3 | 20020517 | Product specification | - | 74HC_HCT1G04 v.2 | | |
| 74HC_HCT1G04 v.2 | 20010302 | Product specification | - | 74HC_HCT1G04 v.1 | | |
| 74HC_HCT1G04 v.1 | 19980831 | Preliminary specification | - | - | | |
| | | | | | | |

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16. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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[2] The term 'short data sheet' is explained in section "Definitions".

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